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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	516096
Number of I/O	620
Number of Gates	300000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	896-BGA
Supplier Device Package	896-FBGA (31x31)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m1a3pe3000-1fgg896i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



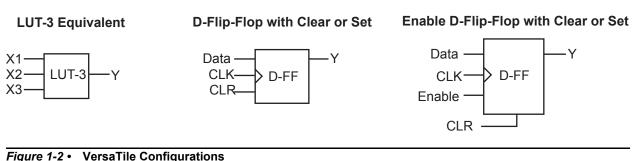
ProASIC3E Device Family Overview

#### VersaTiles

The ProASIC3E core consists of VersaTiles, which have been enhanced beyond the ProASIC<sup>PLUS®</sup> core tiles. The ProASIC3E VersaTile supports the following:

- All 3-input logic functions—LUT-3 equivalent
- Latch with clear or set
- D-flip-flop with clear or set
- Enable D-flip-flop with clear or set

Refer to Figure 1-2 for VersaTile configurations.



#### User Nonvolatile FlashROM

ProASIC3E devices have 1 kbit of on-chip, user-accessible, nonvolatile FlashROM. The FlashROM can be used in diverse system applications:

- · Internet protocol addressing (wireless or fixed)
- System calibration settings
- Device serialization and/or inventory control
- Subscription-based business models (for example, set-top boxes)
- · Secure key storage for secure communications algorithms
- Asset management/tracking
- Date stamping
- Version management

The FlashROM is written using the standard ProASIC3E IEEE 1532 JTAG programming interface. The core can be individually programmed (erased and written), and on-chip AES decryption can be used selectively to securely load data over public networks, as in security keys stored in the FlashROM for a user design.

The FlashROM can be programmed via the JTAG programming interface, and its contents can be read back either through the JTAG programming interface or via direct FPGA core addressing. Note that the FlashROM can only be programmed from the JTAG interface and cannot be programmed from the internal logic array.

The FlashROM is programmed as 8 banks of 128 bits; however, reading is performed on a byte-by-byte basis using a synchronous interface. A 7-bit address from the FPGA core defines which of the 8 banks and which of the 16 bytes within that bank are being read. The three most significant bits (MSBs) of the FlashROM address determine the bank, and the four least significant bits (LSBs) of the FlashROM address define the byte.

The ProASIC3E development software solutions, Libero<sup>®</sup> System-on-Chip (SoC) and Designer, have extensive support for the FlashROM. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature allows the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using Libero SoC and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.

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ProASIC3E DC and Switching Characteristics

### Table 2-9 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings (continued) (continued)<sup>1</sup>

	C <sub>LOAD</sub> (pF)	VCCI (V)	Static Power PDC3 (mW) <sup>2</sup>	Dynamic Power PAC10 (µW/MHz) <sup>3</sup>
SSTL3 (I)	30	3.3	26.02	114.87
SSTL3 (II)	30	3.3	42.21	131.76
Differential	•			
LVDS/B-LVDS/M-LVDS	-	2.5	7.70	89.62
LVPECL	-	3.3	19.42	168.02
Notes:	•		1	1

1. Dynamic power consumption is given for standard load and software default drive strength and output slew.

2. PDC3 is the static power (where applicable) measured on VCCI.

3. PAC10 is the total dynamic power measured on VCC and VCCI.

4. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.

### **Power Consumption of Various Internal Resources**

Table 2-10 • Different Components Contributing to the Dynamic Power Consumption in ProASIC3E Devices

		Device-Specific Dynamic Contributions (µW/MHz)					
Parameter	Definition	A3PE600	A3PE1500	A3PE3000			
PAC1	Clock contribution of a Global Rib	12.77	16.21	19.7			
PAC2	Clock contribution of a Global Spine	1.85	3.06	4.16			
PAC3	Clock contribution of a VersaTile row		0.88				
PAC4	Clock contribution of a VersaTile used as a sequential module		0.12				
PAC5	First contribution of a VersaTile used as a sequential 0.07 module						
PAC6	Second contribution of a VersaTile used as a sequential module	0.29					
PAC7	Contribution of a VersaTile used as a combinatorial module		0.29				
PAC8	Average contribution of a routing net		0.70				
PAC9	Contribution of an I/O input pin (standard-dependent)	See 7	Table 2-8 on pag	ge 2-6.			
PAC10	Contribution of an I/O output pin (standard-dependent)	See	Table 2-9 on pag	ge 2-7			
PAC11	Average contribution of a RAM block during a read operation	25.00					
PAC12	Average contribution of a RAM block during a write operation	30.00					
PAC13	Static PLL contribution	2.55 mW					
PAC14	Dynamic contribution for PLL	2.60					

Note: For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power calculator or SmartPower in Libero SoC.

### 3.3 V LVCMOS Wide Range

3.3 V LVCMOS Wide Range	Equivalent Software Default Drive	v	IL	v	н	VOL	VOH	IOL	юн	IOSL	IOSH	IIL <sup>2</sup>	IIH <sup>3</sup>
Drive Strength	Strength Option <sup>1</sup>	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	μA	μA	Max. mA <sup>4</sup>	Max. mA <sup>4</sup>	μA <sup>5</sup>	μA <sup>5</sup>
100 µA	2 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	27	25	10	10
100 µA	4 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	27	25	10	10
100 µA	6 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	54	51	10	10
100 µA	8 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	54	51	10	10
100 µA	12 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	109	103	10	10
100 µA	16 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	127	132	10	10
100 µA	24 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	181	268	10	10

#### Table 2-29 • Minimum and Maximum DC Input and Output Levels

Notes:

1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

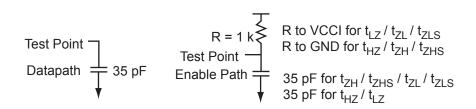
2. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.

3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN< VCCI. Input current is larger when operating outside recommended ranges.

4. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.

5. Currents are measured at 85°C junction temperature.

6. Software default selection highlighted in gray.



#### Figure 2-7 • AC Loading

#### Table 2-30 • 3.3 V LVCMOS Wide Range AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	1.4	_	35

*Note:* \**Measuring point = Vtrip. See Table 2-15 on page 2-18 for a complete table of trip points.* 

### **Differential I/O Characteristics**

#### Physical Implementation

Configuration of the I/O modules as a differential pair is handled by the Designer software when the user instantiates a differential I/O macro in the design.

Differential I/Os can also be used in conjunction with the embedded Input Register (InReg), Output Register (OutReg), Enable Register (EnReg), and DDR. However, there is no support for bidirectional I/Os or tristates with the LVPECL standards.

#### LVDS

Low-Voltage Differential Signaling (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard. It requires that one data bit be carried through two signal lines, so two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-22. The building blocks of the LVDS transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVPECL implementation because the output standard specifications are different.

Along with LVDS I/O, ProASIC3E also supports Bus LVDS structure and Multipoint LVDS (M-LVDS) configuration (up to 40 nodes).

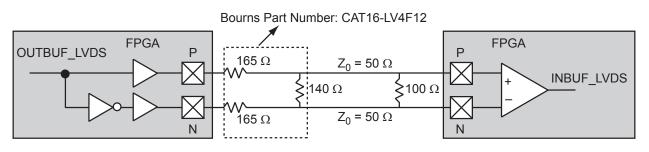
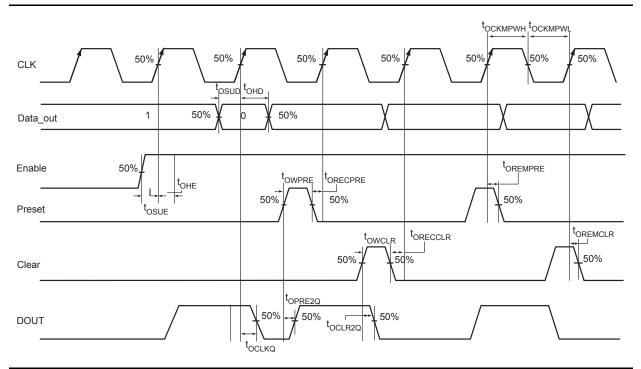


Figure 2-22 • LVDS Circuit Diagram and Board-Level Implementation

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ProASIC3E DC and Switching Characteristics

### **Output Register**





#### **Timing Characteristics**

Table 2-87 • Output Data Register Propagation DelaysCommercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	0.59	0.67	0.79	ns
t <sub>OSUD</sub>	Data Setup Time for the Output Data Register	0.31	0.36	0.42	ns
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>OSUE</sub>	Enable Setup Time for the Output Data Register	0.44	0.50	0.59	ns
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	0.80	0.91	1.07	ns
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	0.80	0.91	1.07	ns
t <sub>OREMCLR</sub>	Asynchronous Clear Removal Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>ORECCLR</sub>	Asynchronous Clear Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OREMPRE</sub>	Asynchronous Preset Removal Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OCKMPWH</sub>	Clock Minimum Pulse Width High for the Output Data Register	0.36	0.41	0.48	ns
t <sub>OCKMPWL</sub>	Clock Minimum Pulse Width Low for the Output Data Register	0.32	0.37	0.43	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

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ProASIC3E DC and Switching Characteristics

### **Timing Characteristics**

#### Table 2-101 • FIFO

Commercial-Case Conditions:  $T_J = 70^{\circ}C$ , VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>ENS</sub>	REN, WEN Setup Time	1.38	1.57	1.84	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.02	0.02	0.02	ns
t <sub>BKS</sub>	BLK Setup Time	0.19	0.22	0.26	ns
t <sub>BKH</sub>	BLK Hold Time	0.00	0.00	0.00	ns
t <sub>DS</sub>	Input Data (WD) Setup Time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input Data (WD) Hold Time	0.00	0.00	0.00	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on RD (pass-through)	2.36	2.68	3.15	ns
t <sub>CKQ2</sub>	Clock High to New Data Valid on RD (pipelined)	0.89	1.02	1.20	ns
t <sub>RCKEF</sub>	RCLK High to Empty Flag Valid	1.72	1.96	2.30	ns
t <sub>WCKFF</sub>	WCLK High to Full Flag Valid	1.63	1.86	2.18	ns
t <sub>CKAF</sub>	Clock High to Almost Empty/Full Flag Valid	6.19	7.05	8.29	ns
t <sub>RSTFG</sub>	RESET Low to Empty/Full Flag Valid	1.69	1.93	2.27	ns
t <sub>RSTAF</sub>	RESET Low to Almost Empty/Full Flag Valid	6.13	6.98	8.20	ns
t <sub>RSTBQ</sub>	RESET Low to Data Out Low on RD (pass-through)	0.92	1.05	1.23	ns
	RESET Low to Data Out Low on RD (pipelined)	0.92	1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET Removal	0.29	0.33	0.38	ns
t <sub>RECRSTB</sub>	RESET Recovery	1.50	1.71	2.01	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	0.21	0.24	0.29	ns
t <sub>CYC</sub>	Clock Cycle Time	3.23	3.68	4.32	ns
F <sub>MAX</sub>	Maximum Frequency	310	272	231	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.



## 3 – Pin Descriptions and Packaging

### **Supply Pins**

#### GND

#### Ground

Ground supply voltage to the core, I/O outputs, and I/O logic.

#### GNDQ

#### Ground (quiet)

Quiet ground supply voltage to input buffers of I/O banks. Within the package, the GNDQ plane is decoupled from the simultaneous switching noise originated from the output buffer ground domain. This minimizes the noise transfer within the package and improves input signal integrity. GNDQ must always be connected to GND on the board.

#### VCC

#### **Core Supply Voltage**

Supply voltage to the FPGA core, nominally 1.5 V. VCC is required for powering the JTAG state machine in addition to VJTAG. Even when a device is in bypass mode in a JTAG chain of interconnected devices, both VCC and VJTAG must remain powered to allow JTAG signals to pass through the device.

#### VCCIBx

#### I/O Supply Voltage

Supply voltage to the bank's I/O output buffers and I/O logic. Bx is the I/O bank number. There are up to eight I/O banks on low power flash devices plus a dedicated VJTAG bank. Each bank can have a separate VCCI connection. All I/Os in a bank will run off the same VCCIBx supply. VCCI can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. In general, unused I/O banks should have their corresponding VCCIX pins tied to GND. If an output pad is terminated to ground through any resistor and if the corresponding VCCIX is left floating, then the leakage current to ground is ~ 0uA. However, if an output pad is terminated to ground is ~ 0uA. However, if an output pad is terminated to ground is ~ 3 uA. For unused banks the aforementioned behavior is to be taken into account while deciding if it's better to float VCCIX of unused bank or tie it to GND.

#### VMVx

#### I/O Supply Voltage (quiet)

Quiet supply voltage to the input buffers of each I/O bank. *x* is the bank number. Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks. This minimizes the noise transfer within the package and improves input signal integrity. Each bank must have at least one VMV connection, and no VMV should be left unconnected. All I/Os in a bank run off the same VMVx supply. VMV is used to provide a quiet supply voltage to the input buffers of each I/O bank. VMVx can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VMV pins tied to GND. VMV and VCCI should be at the same voltage within a given I/O bank. Used VMV pins must be connected to the corresponding VCCI pins of the same bank (i.e., VMV0 to VCCIB0, VMV1 to VCCIB1, etc.).

#### VCCPLA/B/C/D/E/F

#### PLL Supply Voltage

Supply voltage to analog PLL, nominally 1.5 V.

When the PLLs are not used, the place-and-route tool automatically disables the unused PLLs to lower power consumption. The user should tie unused VCCPLx and VCOMPLx pins to ground. Microsemi recommends tying VCCPLx to VCC and using proper filtering circuits to decouple VCC noise from the PLLs. Refer to the PLL Power Supply Decoupling section of the "Clock Conditioning Circuits in Low Power Flash Devices and Mixed Signal FPGAs" chapter of the *ProASIC3E FPGA Fabric User's Guide* for a complete board solution for the PLL analog power supply and ground.

There are six VCCPLX pins on ProASIC3E devices.

#### VCOMPLA/B/C/D/E/F PLL Ground

Ground to analog PLL power supplies. When the PLLs are not used, the place-and-route tool automatically disables the unused PLLs to lower power consumption. The user should tie unused VCCPLx and VCOMPLx pins to ground.

There are six VCOMPL pins (PLL ground) on ProASIC3E devices.



Pin Descriptions and Packaging

#### VJTAG

#### JTAG Supply Voltage

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND. It should be noted that VCC is required to be powered for JTAG operation; VJTAG alone is insufficient. If a device is in a JTAG chain of interconnected boards, the board containing the device can be powered down, provided both VJTAG and VCC to the part remain powered; otherwise, JTAG signals will not be able to transition the device, even in bypass mode.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

#### VPUMP Programming Supply Voltage

For programming, VPUMP should be 3.3 V nominal. During normal device operation, VPUMP can be left floating or can be tied (pulled up) to any voltage between 0 V and the VPUMP maximum. Programming power supply voltage (VPUMP) range is listed in the datasheet.

When the VPUMP pin is tied to ground, it will shut off the charge pump circuitry, resulting in no sources of oscillation from the charge pump circuitry.

For proper programming, 0.01  $\mu$ F and 0.33  $\mu$ F capacitors (both rated at 16 V) are to be connected in parallel across VPUMP and GND, and positioned as close to the FPGA pins as possible.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

### **User-Defined Supply Pins**

#### VREF

#### I/O Voltage Reference

Reference voltage for I/O minibanks. VREF pins are configured by the user from regular I/Os, and any I/O in a bank, except JTAG I/Os, can be designated the voltage reference I/O. Only certain I/O standards require a voltage reference—HSTL (I) and (II), SSTL2 (I) and (II), SSTL3 (I) and (II), and GTL/GTL+. One VREF pin can support the number of I/Os available in its minibank.

### **User Pins**

#### I/O

#### User Input/Output

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Input and output signal levels are compatible with the I/O standard selected.

During programming, I/Os become tristated and weakly pulled up to VCCI. With VCCI, VMV, and VCC supplies continuously powered up, when the device transitions from programming to operating mode, the I/Os are instantly configured to the desired user configuration.

Unused I/Os are configured as follows:

- Output buffer is disabled (with tristate value of high impedance)
- Input buffer is disabled (with tristate value of high impedance)
- Weak pull-up is programmed

#### GL Globals

GL I/Os have access to certain clock conditioning circuitry (and the PLL) and/or have direct access to the global network (spines). Additionally, the global I/Os can be used as regular I/Os, since they have identical capabilities. Unused GL pins are configured as inputs with pull-up resistors.

See more detailed descriptions of global I/O connectivity in the "Clock Conditioning Circuits in Low Power Flash Devices and Mixed Signal FPGAs" chapter of the *ProASIC3E FPGA Fabric User's Guide*. All inputs labeled GC/GF are direct inputs into the quadrant clocks. For example, if GAA0 is used for an input, GAA1 and GAA2 are no longer available for input to the quadrant globals. All inputs labeled GC/GF are direct inputs into the chip-level globals, and the rest are connected to the quadrant globals. The inputs to the global network are multiplexed, and only one input can be used as a global input.

Refer to the I/O Structure section of the *ProASIC3E FPGA Fabric User's Guide* for an explanation of the naming of global pins.

### **JTAG Pins**

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the part must be supplied to allow JTAG signals to transition the device. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND.

#### TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pullup/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500 W to 1 k $\Omega$  will satisfy the requirements. Refer to Table 3-1 for more information.

VJTAG	Tie-Off Resistance
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 $\Omega$ to 1 k $\Omega$
VJTAG at 1.5 V	500 Ω to 1 kΩ

#### Table 3-1 • Recommended Tie-Off Values for the TCK and TRST Pins

Notes:

- 1. Equivalent parallel resistance if more than one device is on the JTAG chain
- 2. The TCK pin can be pulled up/down.
- 3. The TRST pin is pulled down.

#### TDI

TMS

#### Test Data Input

**Test Data Output** 

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

#### TDO

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

#### Test Mode Select

The TMS pin controls the use of the IEEE 1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

#### TRST Boundary Scan Reset Pin

The TRST pin functions as an active-low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the test access port (TAP) is held in reset mode. The resistor values must be chosen from Table 3-1 and must satisfy the parallel resistance value requirement. The values in Table 3-1 correspond to the resistor recommended when a single device is used, and the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entrance to an undesired JTAG state. In such cases, Microsemi recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all VJTAG voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements.

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FG484			FG484		FG484			
Pin Number A3PE1500 Function		Pin Number	A3PE1500 Function	Pin Number	A3PE1500 Function			
A1	GND	AA15	NC	B7	IO10PDB0V1			
A2	GND	AA16	IO117NDB4V0	B8	IO15NDB0V1			
A3	VCCIB0	AA17	IO117PDB4V0	B9	IO17NDB0V2			
A4	IO05NDB0V0	AA18	IO115NDB4V0	B10	IO20PDB0V2			
A5	IO05PDB0V0	AA19	IO115PDB4V0	B11	IO29PDB0V3			
A6	IO11NDB0V1	AA20	NC	B12	IO32NDB1V0			
A7	IO11PDB0V1	AA21	VCCIB3	B13	IO43NDB1V1			
A8	IO15PDB0V1	AA22	GND	B14	NC			
A9	IO17PDB0V2	AB1	GND	B15	NC			
A10	IO27NDB0V3	AB2	GND	B16	IO53NDB1V2			
A11	IO27PDB0V3	AB3	VCCIB5	B17	IO53PDB1V2			
A12	IO32PDB1V0	AB4	IO159NDB5V3	B18	IO54PDB1V3			
A13	IO43PDB1V1	AB5	IO159PDB5V3	B19	NC			
A14	IO47NDB1V1	AB6	IO149NDB5V1	B20	NC			
A15	IO47PDB1V1	AB7	IO149PDB5V1	B21	VCCIB2			
A16	IO51NDB1V2	AB8	IO138NDB5V0	B22	GND			
A17	IO51PDB1V2	AB9	IO138PDB5V0	C1	VCCIB7			
A18	IO54NDB1V3	AB10	NC	C2	NC			
A19	NC	AB11	NC	C3	NC			
A20	VCCIB1	AB12	IO127NDB4V2	C4	NC			
A21	GND	AB13	IO127PDB4V2	C5	GND			
A22	GND	AB14	IO125NDB4V1	C6	IO07NDB0V0			
AA1	GND	AB15	IO125PDB4V1	C7	IO07PDB0V0			
AA2	VCCIB6	AB16	IO122NDB4V1	C8	VCC			
AA3	NC	AB17	IO122PDB4V1	C9	VCC			
AA4	IO161PDB5V3	AB18	NC	C10	IO20NDB0V2			
AA5	IO155NDB5V2	AB19	NC	C11	IO29NDB0V3			
AA6	IO155PDB5V2	AB20	VCCIB4	C12	NC			
AA7	IO154NDB5V2	AB21	GND	C13	NC			
AA8	IO154PDB5V2	AB22	GND	C14	VCC			
AA9	IO143PDB5V1	B1	GND	C15	VCC			
AA10	IO143NDB5V1	B2	VCCIB7	C16	NC			
AA11	IO131PPB4V2	B3	NC	C17	NC			
AA12	IO129NDB4V2	B4	IO03NDB0V0	C18	GND			
AA13	IO129PDB4V2	B5	IO03PDB0V0	C19	NC			
AA14	NC	B6	IO10NDB0V1	C20	NC			



	FG484		FG484		FG484
Pin Number	A3PE1500 Function	Pin Number	A3PE1500 Function	Pin Number	A3PE1500 Function
C21	NC	E13	IO41NDB1V1	G5	IO217PDB7V3
C22	VCCIB2	E14	IO41PDB1V1	G6	GAC2/IO219PDB7V3
D1	NC	E15	GBC1/IO55PDB1V3	G7	VCOMPLA
D2	NC	E16	GBB0/IO56NDB1V3	G8	GNDQ
D3	NC	E17	GNDQ	G9	IO19NDB0V2
D4	GND	E18	GBA2/IO58PDB2V0	G10	IO19PDB0V2
D5	GAA0/IO00NDB0V0	E19	IO63NDB2V0	G11	IO25PDB0V3
D6	GAA1/IO00PDB0V0	E20	GND	G12	IO33PDB1V0
D7	GAB0/IO01NDB0V0	E21	IO69NDB2V1	G13	IO39PDB1V0
D8	IO09PDB0V1	E22	NC	G14	IO45NDB1V1
D9	IO13PDB0V1	F1	IO218NPB7V3	G15	GNDQ
D10	IO21PDB0V2	F2	IO216NDB7V3	G16	VCOMPLB
D11	IO31NDB0V3	F3	IO216PDB7V3	G17	GBB2/IO59PDB2V0
D12	IO37NDB1V0	F4	IO220NDB7V3	G18	IO62PDB2V0
D13	IO37PDB1V0	F5	IO221NDB7V3	G19	IO62NDB2V0
D14	IO49NDB1V2	F6	VMV7	G20	IO71PDB2V2
D15	IO49PDB1V2	F7	VCCPLA	G21	IO71NDB2V2
D16	GBB1/IO56PDB1V3	F8	GAC0/IO02NDB0V0	G22	NC
D17	GBA0/IO57NDB1V3	F9	GAC1/IO02PDB0V0	H1	IO209PSB7V2
D18	GBA1/IO57PDB1V3	F10	IO23NDB0V2	H2	NC
D19	GND	F11	IO23PDB0V2	H3	VCC
D20	NC	F12	IO35PDB1V0	H4	IO214NDB7V3
D21	IO69PDB2V1	F13	IO39NDB1V0	H5	IO217NDB7V3
D22	NC	F14	IO45PDB1V1	H6	IO219NDB7V3
E1	NC	F15	GBC0/IO55NDB1V3	H7	IO215PDB7V3
E2	IO218PPB7V3	F16	VCCPLB	H8	VMV0
E3	GND	F17	VMV2	H9	VCCIB0
E4	GAB2/IO220PDB7V3	F18	IO58NDB2V0	H10	VCCIB0
E5	GAA2/IO221PDB7V3	F19	IO63PDB2V0	H11	IO25NDB0V3
E6	GNDQ	F20	NC	H12	IO33NDB1V0
E7	GAB1/IO01PDB0V0	F21	NC	H13	VCCIB1
E8	IO09NDB0V1	F22	NC	H14	VCCIB1
E9	IO13NDB0V1	G1	IO211NDB7V2	H15	VMV1
E10	IO21NDB0V2	G2	IO211PDB7V2	H16	GBC2/IO60PDB2V0
E11	IO31PDB0V3	G3	NC	H17	IO59NDB2V0
E12	IO35NDB1V0	G4	IO214PDB7V3	H18	IO67NDB2V1



FG484			FG484	FG484			
Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function		
C21	IO94PPB2V1	E13	IO58NDB1V2	G5	IO297PDB7V2		
C22	VCCIB2	E14	IO58PDB1V2	G6	GAC2/IO307PDB7V4		
D1	IO293PDB7V2	E15	GBC1/IO79PDB1V4	G7	VCOMPLA		
D2	IO303NDB7V3	E16	GBB0/IO80NDB1V4	G8	GNDQ		
D3	IO305NDB7V3	E17	GNDQ	G9	IO26NDB0V3		
D4	GND	E18	GBA2/IO82PDB2V0	G10	IO26PDB0V3		
D5	GAA0/IO00NDB0V0	E19	IO86NDB2V0	G11	IO36PDB0V4		
D6	GAA1/IO00PDB0V0	E20	GND	G12	IO42PDB1V0		
D7	GAB0/IO01NDB0V0	E21	IO90NDB2V1	G13	IO50PDB1V1		
D8	IO20PDB0V2	E22	IO98PDB2V2	G14	IO60NDB1V2		
D9	IO22PDB0V2	F1	IO299NPB7V3	G15	GNDQ		
D10	IO30PDB0V3	F2	IO301NDB7V3	G16	VCOMPLB		
D11	IO38NDB0V4	F3	IO301PDB7V3	G17	GBB2/IO83PDB2V0		
D12	IO52NDB1V1	F4	IO308NDB7V4	G18	IO92PDB2V1		
D13	IO52PDB1V1	F5	IO309NDB7V4	G19	IO92NDB2V1		
D14	IO66NDB1V3	F6	VMV7	G20	IO102PDB2V2		
D15	IO66PDB1V3	F7	VCCPLA	G21	IO102NDB2V2		
D16	GBB1/IO80PDB1V4	F8	GAC0/IO02NDB0V0	G22	IO105NDB2V2		
D17	GBA0/IO81NDB1V4	F9	GAC1/IO02PDB0V0	H1	IO286PSB7V1		
D18	GBA1/IO81PDB1V4	F10	IO32NDB0V3	H2	IO291NPB7V2		
D19	GND	F11	IO32PDB0V3	H3	VCC		
D20	IO88PDB2V0	F12	IO44PDB1V0	H4	IO295NDB7V2		
D21	IO90PDB2V1	F13	IO50NDB1V1	H5	IO297NDB7V2		
D22	IO94NPB2V1	F14	IO60PDB1V2	H6	IO307NDB7V4		
E1	IO293NDB7V2	F15	GBC0/IO79NDB1V4	H7	IO287PDB7V1		
E2	IO299PPB7V3	F16	VCCPLB	H8	VMV0		
E3	GND	F17	VMV2	H9	VCCIB0		
E4	GAB2/IO308PDB7V4	F18	IO82NDB2V0	H10	VCCIB0		
E5	GAA2/IO309PDB7V4	F19	IO86PDB2V0	H11	IO36NDB0V4		
E6	GNDQ	F20	IO96PDB2V1	H12	IO42NDB1V0		
E7	GAB1/IO01PDB0V0	F21	IO96NDB2V1	H13	VCCIB1		
E8	IO20NDB0V2	F22	IO98NDB2V2	H14	VCCIB1		
E9	IO22NDB0V2	G1	IO289NDB7V1	H15	VMV1		
E10	IO30NDB0V3	G2	IO289PDB7V1	H16	GBC2/IO84PDB2V0		
E11	IO38PDB0V4	G3	IO291PPB7V2	H17	IO83NDB2V0		
E12	IO44NDB1V0	G4	IO295PDB7V2	H18	IO100NDB2V2		



	FG484		FG484	FG484			
Pin Number A3PE3000 Function		Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function		
N17	IO132NPB3V2	R9	VCCIB5	U1	IO240PPB6V0		
N18	IO117NPB3V0	R10	VCCIB5	U2	IO238PDB6V0		
N19	IO132PPB3V2	R11	IO196NDB5V0	U3	IO238NDB6V0		
N20	GNDQ	R12	IO196PDB5V0	U4	GEB1/IO235PDB6V0		
N21	IO126NDB3V1	R13	VCCIB4	U5	GEB0/IO235NDB6V0		
N22	IO128PDB3V1	R14	VCCIB4	U6	VMV6		
P1	IO247PDB6V1	R15	VMV3	U7	VCCPLE		
P2	IO253PDB6V2	R16	VCCPLD	U8	IO233NPB5V4		
P3	IO270NPB6V4	R17	GDB1/IO152PPB3V4	U9	IO222PPB5V3		
P4	IO261NPB6V3	R18	GDC1/IO151PDB3V4	U10	IO206PDB5V1		
P5	IO249PPB6V1	R19	IO138NDB3V3	U11	IO202PDB5V1		
P6	IO259PDB6V3	R20	VCC	U12	IO194PDB5V0		
P7	IO259NDB6V3	R21	IO130NDB3V2	U13	IO176NDB4V2		
P8	VCCIB6	R22	IO134PDB3V2	U14	IO176PDB4V2		
P9	GND	T1	IO243PPB6V1	U15	VMV4		
P10	VCC	T2	IO245NDB6V1	U16	ТСК		
P11	VCC	Т3	IO243NPB6V1	U17	VPUMP		
P12	VCC	T4	IO241PDB6V0	U18	TRST		
P13	VCC	T5	IO241NDB6V0	U19	GDA0/IO153NDB3V4		
P14	GND	Т6	GEC1/IO236PPB6V0	U20	IO144NDB3V3		
P15	VCCIB3	T7	VCOMPLE	U21	IO140NDB3V3		
P16	GDB0/IO152NPB3V4	Т8	GNDQ	U22	IO142PDB3V3		
P17	IO136NDB3V2	Т9	GEA2/IO233PPB5V4	V1	IO239PDB6V0		
P18	IO136PDB3V2	T10	IO206NDB5V1	V2	IO240NPB6V0		
P19	IO138PDB3V3	T11	IO202NDB5V1	V3	GND		
P20	VMV3	T12	IO194NDB5V0	V4	GEA1/IO234PDB6V0		
P21	IO130PDB3V2	T13	IO186NDB4V4	V5	GEA0/IO234NDB6V0		
P22	IO128NDB3V1	T14	IO186PDB4V4	V6	GNDQ		
R1	IO247NDB6V1	T15	GNDQ	V7	GEC2/IO231PDB5V4		
R2	IO245PDB6V1	T16	VCOMPLD	V8	IO222NPB5V3		
R3	VCC	T17	VJTAG	V9	IO204NDB5V1		
R4	IO249NPB6V1	T18	GDC0/IO151NDB3V4	V10	IO204PDB5V1		
R5	IO251NDB6V2	T19	GDA1/IO153PDB3V4	V11	IO195NDB5V0		
R6	IO251PDB6V2	T20	IO144PDB3V3	V12	IO195PDB5V0		
R7	GEC0/IO236NPB6V0	T21	IO140PDB3V3	V13	IO178NDB4V3		
R8	VMV5	T22	IO134NDB3V2	V14	IO178PDB4V3		



	FG676
Pin Number	A3PE1500 Function
W25	IO96PDB3V1
W26	IO94NDB3V0
Y1	IO175NDB6V1
Y2	IO175PDB6V1
Y3	IO173NDB6V0
Y4	IO173PDB6V0
Y5	GEC1/IO169PPB6V0
Y6	GNDQ
Y7	VMV6
Y8	VCCIB5
Y9	IO163NDB5V3
Y10	IO159PDB5V3
Y11	IO153PDB5V2
Y12	IO147PDB5V1
Y13	IO139PDB5V0
Y14	IO137PDB5V0
Y15	IO125NDB4V1
Y16	IO125PDB4V1
Y17	IO115NDB4V0
Y18	IO115PDB4V0
Y19	VCC
Y20	VPUMP
Y21	VCOMPLD
Y22	VCCPLD
Y23	IO100NDB3V1
Y24	IO100PDB3V1
Y25	IO96NDB3V1
Y26	IO98PDB3V1



	FG896		FG896		FG896
Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function
AG9	IO225NPB5V3	AH15	IO195NDB5V0	AJ21	IO173PDB4V2
AG10	IO223NPB5V3	AH16	IO185NDB4V3	AJ22	IO163NDB4V1
AG11	IO221PDB5V3	AH17	IO185PDB4V3	AJ23	IO163PDB4V1
AG12	IO221NDB5V3	AH18	IO181PDB4V3	AJ24	IO167NPB4V1
AG13	IO205NPB5V1	AH19	IO177NDB4V2	AJ25	VCC
AG14	IO199NDB5V0	AH20	IO171NPB4V2	AJ26	IO156NPB4V0
AG15	IO199PDB5V0	AH21	IO165PPB4V1	AJ27	VCC
AG16	IO187NDB4V4	AH22	IO161PPB4V0	AJ28	TMS
AG17	IO187PDB4V4	AH23	IO157NDB4V0	AJ29	GND
AG18	IO181NDB4V3	AH24	IO157PDB4V0	AJ30	GND
AG19	IO171PPB4V2	AH25	IO155NDB4V0	AK2	GND
AG20	IO165NPB4V1	AH26	VCCIB4	AK3	GND
AG21	IO161NPB4V0	AH27	TDI	AK4	IO217PPB5V2
AG22	IO159NDB4V0	AH28	VCC	AK5	GND
AG23	IO159PDB4V0	AH29	VPUMP	AK6	IO215PPB5V2
AG24	IO158PPB4V0	AH30	GND	AK7	GND
AG25	GDB2/IO155PDB4V0	AJ1	GND	AK8	IO207NDB5V1
AG26	GDA2/IO154PPB4V0	AJ2	GND	AK9	IO207PDB5V1
AG27	GND	AJ3	GEA2/IO233PPB5V4	AK10	IO201NDB5V0
AG28	VJTAG	AJ4	VCC	AK11	IO201PDB5V0
AG29	VCC	AJ5	IO217NPB5V2	AK12	IO193NDB4V4
AG30	IO149NDB3V4	AJ6	VCC	AK13	IO193PDB4V4
AH1	GND	AJ7	IO215NPB5V2	AK14	IO197PDB5V0
AH2	IO233NPB5V4	AJ8	IO213NDB5V2	AK15	IO191NDB4V4
AH3	VCC	AJ9	IO213PDB5V2	AK16	IO191PDB4V4
AH4	GEB2/IO232PPB5V4	AJ10	IO209NDB5V1	AK17	IO189NDB4V4
AH5	VCCIB5	AJ11	IO209PDB5V1	AK18	IO189PDB4V4
AH6	IO219NDB5V3	AJ12	IO203NDB5V1	AK19	IO179PPB4V3
AH7	IO219PDB5V3	AJ13	IO203PDB5V1	AK20	IO175NDB4V2
AH8	IO227NDB5V4	AJ14	IO197NDB5V0	AK21	IO175PDB4V2
AH9	IO227PDB5V4	AJ15	IO195PDB5V0	AK22	IO169NDB4V1
AH10	IO225PPB5V3	AJ16	IO183NDB4V3	AK23	IO169PDB4V1
AH11	IO223PPB5V3	AJ17	IO183PDB4V3	AK24	GND
AH12	IO211NDB5V2	AJ18	IO179NPB4V3	AK25	IO167PPB4V1
AH13	IO211PDB5V2	AJ19	IO177PDB4V2	AK26	GND
AH14	IO205PPB5V1	AJ20	IO173NDB4V2	AK27	GDC2/IO156PPB4V0



	FG896	FG896		FG896	
Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function
J5	IO295NDB7V2	K11	IO04PPB0V0	L17	VCC
J6	IO299NDB7V3	K12	VCCIB0	L18	VCC
J7	VCCIB7	K13	VCCIB0	L19	VCC
J8	VCCPLA	K14	VCCIB0	L20	VCC
J9	VCC	K15	VCCIB0	L21	IO78NPB1V4
J10	IO04NPB0V0	K16	VCCIB1	L22	IO104NPB2V2
J11	IO18NDB0V2	K17	VCCIB1	L23	IO98NDB2V2
J12	IO20NDB0V2	K18	VCCIB1	L24	IO98PDB2V2
J13	IO20PDB0V2	K19	VCCIB1	L25	IO87PDB2V0
J14	IO32NDB0V3	K20	IO76PPB1V4	L26	IO87NDB2V0
J15	IO32PDB0V3	K21	VCC	L27	IO97PDB2V1
J16	IO42PDB1V0	K22	IO78PPB1V4	L28	IO101PDB2V2
J17	IO44NDB1V0	K23	IO88NDB2V0	L29	IO103PDB2V2
J18	IO44PDB1V0	K24	IO88PDB2V0	L30	IO119NDB3V0
J19	IO54NDB1V1	K25	IO94PDB2V1	M1	IO282NDB7V1
J20	IO54PDB1V1	K26	IO94NDB2V1	M2	IO282PDB7V1
J21	IO76NPB1V4	K27	IO85PDB2V0	M3	IO292NDB7V2
J22	VCC	K28	IO85NDB2V0	M4	IO292PDB7V2
J23	VCCPLB	K29	IO93PDB2V1	M5	IO283NDB7V1
J24	VCCIB2	K30	IO93NDB2V1	M6	IO285PDB7V1
J25	IO90PDB2V1	L1	IO286NDB7V1	M7	IO287PDB7V1
J26	IO90NDB2V1	L2	IO286PDB7V1	M8	IO289PDB7V1
J27	GBB2/IO83PDB2V0	L3	IO298NDB7V3	M9	IO289NDB7V1
J28	IO83NDB2V0	L4	IO298PDB7V3	M10	VCCIB7
J29	IO91PDB2V1	L5	IO283PDB7V1	M11	VCC
J30	IO91NDB2V1	L6	IO291NDB7V2	M12	GND
K1	IO288NDB7V1	L7	IO291PDB7V2	M13	GND
K2	IO288PDB7V1	L8	IO293PDB7V2	M14	GND
K3	IO304NDB7V3	L9	IO293NDB7V2	M15	GND
K4	IO304PDB7V3	L10	IO307NPB7V4	M16	GND
K5	GAB2/IO308PDB7V4	L11	VCC	M17	GND
K6	IO308NDB7V4	L12	VCC	M18	GND
K7	IO301PDB7V3	L13	VCC	M19	GND
K8	IO301NDB7V3	L14	VCC	M20	VCC
K9	GAC2/IO307PPB7V4	L15	VCC	M21	VCCIB2
K10	VCC	L16	VCC	M22	NC

# 5 – Datasheet Information

### **List of Changes**

The following table lists critical changes that were made in each revision of the ProASIC3E datasheet.

Revision	Changes	Page
Revision 15 (June 2015)	Updated "ProASIC3E Ordering Information". Interchanged the positions of Y- Security Feature and I- Application (Temperature Range) (SAR 67296).	1-111
	Added Note "Only devices with package size greater than or equal to 5x5 are supported".	
	Updated Commercial and Industrial Junction Temperatures (SAR 67588).	
	Added the A3PE3000 package to Table 2-5 (SARs 52320 and 58737).	2-5
	Updated "VCCIBx I/O Supply Voltage" (SAR 43323).	3-1
Revision 14 (May 2014)	Added 2 mA and 6 mA I/O short currents values in"I/O Short Currents IOSH/IOSL" (SAR 56295).	2-22 2-24
	Added 2 mA and 6 mA minimum and maximum DC input and output levels in "Minimum and Maximum DC Input and Output Levels" (SAR 56295).	2-25 2-25
	Added 3.3 V LVTTL / 3.3 V LVCMOS High Slew Commercial-Case Conditions for 2 mA and 6 mA in "3.3 V LVTTL / 3.3 V LVCMOS High Slew" (SAR 56295).	
	Added 3.3 V LVTTL / 3.3 V LVCMOS Low Slew Commercial-Case Conditions for 2 mA and 6 mA in "3.3 V LVTTL / 3.3 V LVCMOS Low Slew" (SAR 56295).	
Revision 13 (January 2013)	In the "Features and Benefits" section, updated the Clock Conditioning Circuit (CCC) and PLL Wide Input Frequency Range from '1.5 MHz to 200 MHz' to '1.5MHz to 350 MHz' based on Table 2-98 (SAR 22196).	1-1
	The "ProASIC3E Ordering Information" section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43220).	1-111
	Added a note to "Recommended Operating Conditions <sup>1</sup> " table (SAR 42716): The programming temperature range supported is $T_{ambient} = 0^{\circ}C$ to 85°C.	2-2
	The note in "ProASIC3E CCC/PLL Specification" table referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42571).	2-70
	Libero Integrated Design Environment (IDE) was changed to Libero System-on- Chip (SoC) throughout the document (SAR 40285).	NA
	Live at Power-Up (LAPU) has been replaced with 'Instant On'.	
Revision 12 (September 2012)	The "Security" section was modified to clarify that Microsemi does not support read-back of programmed data.	1-1



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Revision	Changes	Page
Revision 11 (August 2012)	Added a Note stating "VMV pins must be connected to the corresponding VCCI pins. See the "VMVx I/O Supply Voltage (quiet)" section on page 3-1 for further information." to Table 2-1 • Absolute Maximum Ratings and Table 2-2 • Recommended Operating Conditions <sup>1</sup> (SAR 38322).	2-1 3-1 2-1
	The drive strength, IOL, and IOH value for 3.3 V GTL and 2.5 V GTL was changed from 25 mA to 20 mA in the following tables (SAR 31924): "Summary of Maximum and Minimum DC Input and Output Levels" table "Summary of I/O Timing Characteristics—Software Default Settings" table "I/O Output Buffer Maximum Resistances <sup>1</sup> " table "Minimum and Maximum DC Input and Output Levels" table)	2-16 2-19 2-20 2-39
	"Minimum and Maximum DC Input and Output Levels" table Also added note stating "Output drive strength is below JEDEC specification" for Tables 2-17 and 2-19. Additionally, the IOL and IOH values for 3.3 V GTL+ and 2.5 V GTL+ were corrected from 51 to 35 (for 3.3 V GTL+) and from 40 to 33 (for 2.5 V GTL+) in table Table 2-13 (SAR 39714).	2-40
	"Duration of Short Circuit Event Before Failure" table was revised to change the maximum temperature from 110°C to 100°C, with an example of six months instead of three months (SAR 37934).	2-22
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34796): "It uses a 5 V-tolerant input buffer and push-pull output buffer." This change was made in revision 10 and omitted from the change table in error.	2-30
Revision 11 (continued)	Figure 2-11 was updated to match tables in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section (SAR 34889).	2-38
	In Table 2-81 VIL and VIH were revised so that the maximum is 3.6 V for all listed values of VCCI (SAR 37222).	2-52
	Figure 2-47 and Figure 2-48 are new (SAR 34848).	2-79
	The following sentence was removed from the "VMVx I/O Supply Voltage (quiet)" section in the "Pin Descriptions and Packaging" chapter: "Within the package, the VMV plane is decoupled from the simultaneous switching noise originating from the output buffer VCCI domain" and replaced with "Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks" (SAR 38322). The datasheet mentions that "VMV pins must be connected to the corresponding VCCI pins" for an ESD enhancement.	3-1



Datasheet Information

Revision	Changes	Page
Revision 10 (continued)	"TBD" for 3.3 V LVCMOS Wide Range in Table 2-19 • I/O Output Buffer Maximum Resistances <sup>1</sup> and Table 2-21 • I/O Short Currents IOSH/IOSL was replaced by "Same as regular 3.3 V LVCMOS" (SAR 33853).	
	3.3 V LVCMOS Wide Range information was separated from regular 3.3 V LVCMOS and placed into its own new section, "3.3 V LVCMOS Wide Range". Values of IOSH and IOSL were added in Table 2-29 • Minimum and Maximum DC Input and Output Levels (SAR 33853).	
	The formulas in the table notes for Table 2-20 • I/O Weak Pull-Up/Pull-Down Resistances were corrected (SAR 34755).	2-21
	The AC Loading figures in the "Single-Ended I/O Characteristics" section were updated to match tables in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section (SAR 34889).	2-24
	The titles and subtitles for Table 2-31 • 3.3 V LVCMOS Wide Range High Slew and Table 2-32 • 3.3 V LVCMOS Wide Range Low Slew were corrected (SAR 37227).	2-28, 2-29
	The following notes were removed from Table 2-78 • LVDS Minimum and Maximum DC Input and Output Levels (SAR 34812): ±5%	2-50
	Differential input voltage = ±350 mV	
	Minimum pulse width High and Low values were added to the tables in the "Global Tree Timing Characteristics" section. The maximum frequency for global clock parameter was removed from these tables because a frequency on the global is only an indication of what the global network can do. There are other limiters such as the SRAM, I/Os, and PLL. SmartTime software should be used to determine the design frequency (SAR 36957).	2-68
	A note was added to Table 2-98 • ProASIC3E CCC/PLL Specification indicating that when the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available (SAR 34824).	2-70
	The following figures were deleted. Reference was made to a new application note, <i>Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs</i> , which covers these cases in detail (SAR 34872).	2-74, 2-75, 2-79,
	Figure 2-44 • Write Access after Write onto Same Address	2-82
	Figure 2-45 • Read Access after Write onto Same Address	
	Figure 2-46 • Write Access after Read onto Same Address	
	The port names in the SRAM "Timing Waveforms", SRAM "Timing Characteristics" tables, Figure 2-49 • FIFO Reset, and the FIFO "Timing Characteristics" tables were revised to ensure consistency with the software names (SAR 35750).	
	The "Pin Descriptions and Packaging" chapter is new (SAR 34771).	3-1
	Package names used in the "Package Pin Assignments" section were revised to match standards given in <i>Package Mechanical Drawings</i> (SAR 34771).	4-1
	Pin E6 for the FG256 package was corrected from VvB0 to VCCIB0 (SARs 30364, 31597, 26243).	4-9
July 2010	The versioning system for datasheets has been changed. Datasheets are assigned a revision number that increments each time the datasheet is revised. The "ProASIC3E Device Status" table on page II indicates the status for each device in the device family.	N/A

Revision	Changes	Page
Advance v0.5 (continued)	The "RESET" section was updated.	2-25
	The "RESET" section was updated.	2-27
	The "Introduction" of the "Introduction" section was updated.	2-28
	PCI-X 3.3 V was added to the Compatible Standards for 3.3 V in Table 2- 11 • VCCI Voltages and Compatible Standards	2-29
	Table 2-35 • ProASIC3E I/O Features was updated.	2-54
	The "Double Data Rate (DDR) Support" section was updated to include information concerning implementation of the feature.	2-32
	The "Electrostatic Discharge (ESD) Protection" section was updated to include testing information.	2-35
	Level 3 and 4 descriptions were updated in Table 2-43 • I/O Hot-Swap and 5 V Input Tolerance Capabilities in ProASIC3 Devices.	2-64
	The notes in Table 2-45 • I/O Hot-Swap and 5 V Input Tolerance Capabilities in ProASIC3E Devices were updated.	2-64
	The "Simultaneous Switching Outputs (SSOs) and Printed Circuit Board Layout" section is new.	2-41
	A footnote was added to Table 2-37 • Maximum I/O Frequency for Single-Ended and Differential I/Os in All Banks in ProASIC3E Devices (maximum drive strength and high slew selected).	2-55
	Table 2-48 • ProASIC3E I/O Attributes vs. I/O Standard Applications	2-81
	Table 2-55 • ProASIC3 I/O Standards—SLEW and Output Drive (OUT_DRIVE) Settings	2-85
	The "x" was updated in the "Pin Descriptions" section.	2-50
	The "VCC Core Supply Voltage" pin description was updated.	2-50
	The "VMVx I/O Supply Voltage (quiet)" pin description was updated to include information concerning leaving the pin unconnected.	2-50
	EXTFB was removed from Figure 2-24 • ProASIC3E CCC Options.	2-24
	The CCC Output Peak-to-Peak Period Jitter F <sub>CCC_OUT</sub> was updated in Table 2-13 • ProASIC3E CCC/PLL Specification.	2-30
	EXTFB was removed from Figure 2-27 • CCC/PLL Macro.	2-28
	The LVPECL specification in Table 2-45 • I/O Hot-Swap and 5 V Input Tolerance Capabilities in ProASIC3E Devices was updated.	2-64
	Table 2-15 • Levels of Hot-Swap Support was updated.	2-34
	The "Cold-Sparing Support" section was updated.	2-34
	"Electrostatic Discharge (ESD) Protection" section was updated.	2-35
	The VJTAG and I/O pin descriptions were updated in the "Pin Descriptions" section.	2-50
	The "VJTAG JTAG Supply Voltage" pin description was updated.	2-50
	The "VPUMP Programming Supply Voltage" pin description was updated to include information on what happens when the pin is tied to ground.	2-50